

20 V, single P-channel Trench MOSFET Rev. 3 — 23 March 2012

Product data sheet

1. **Product profile**

1.1 General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006B-3 (SOT883B) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

1.2 Features and benefits

- Very fast switching
- Low threshold voltage
- Trench MOSFET technology

1.3 Applications

- Relay driver
- High-speed line driver

1.4 Quick reference data

- ESD protection up to 2 kV
- Ultra thin package profile of 0.37 mm
- High-side loadswitch
- Switching circuits

Table 1.	Quick reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C	<u>[1]</u>	-	-	-680	mA
Static cha	aracteristics						
R_{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I_{D} = -400 mA; T_{j} = 25 °C		-	0.67	0.85	Ω

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



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2. Pinning information

Table 2.	Pinning	j information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		_
2	S	source		
3	D drain	2 Transparent top view		
			DFN1006B-3 (SOT883B)	s
				017aaa259

3. Ordering information

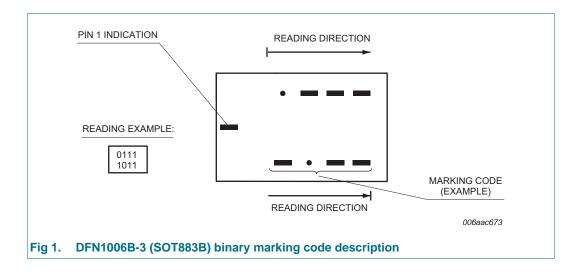
Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMZB670UPE	DFN1006B-3	Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.37 mm	SOT883B				

4. Marking

Table 4. Marking codes	
Type number	Marking code ^[1]
PMZB670UPE	0000 1011

[1] For DFN1006B-3 (SOT883B) binary marking code description see Figure 1.

4.1 Binary marking code description



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5. Limiting values

Table 5. Limiting values

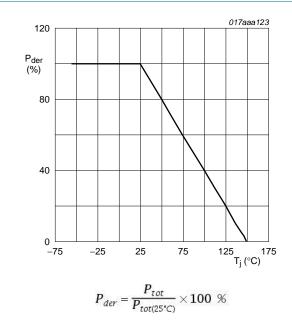
In accordance with the Absolute Maximum Rating System (IEC 60134).

• • •	A 4	A 11/1				
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C	<u>[1]</u>	-	-680	mA
		V _{GS} = -4.5 V; T _{amb} = 100 °C	<u>[1]</u>	-	-425	mA
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-2.7	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	360	mW
			[1]	-	715	mW
		T _{sp} = 25 °C		-	2700	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	diode					
I _S	source current	T _{amb} = 25 °C	<u>[1]</u>	-	-680	mA
ESD maximu	m rating					
V _{ESD}	electrostatic discharge voltage	НВМ	[3]	-	2000	V

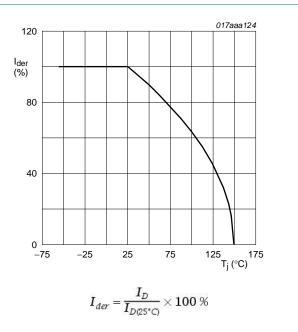
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.



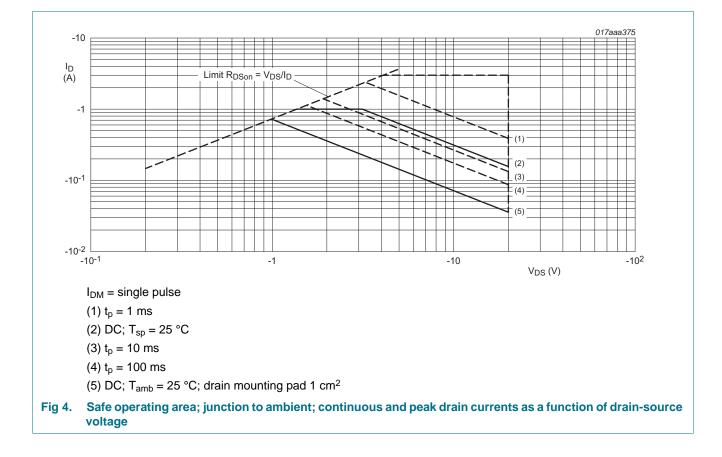






PMZB670UPE

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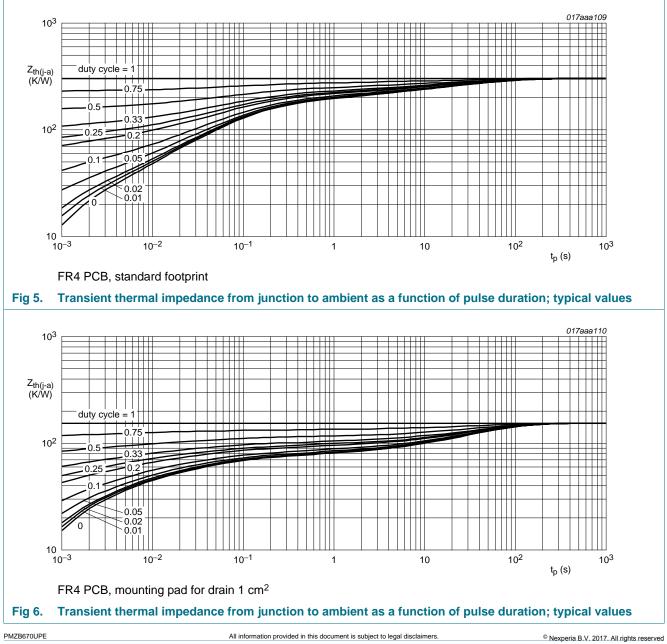


6. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance	in free air	<u>[1]</u>	-	305	360	K/W
	from junction to ambient		[2]	-	150	175	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	40	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².

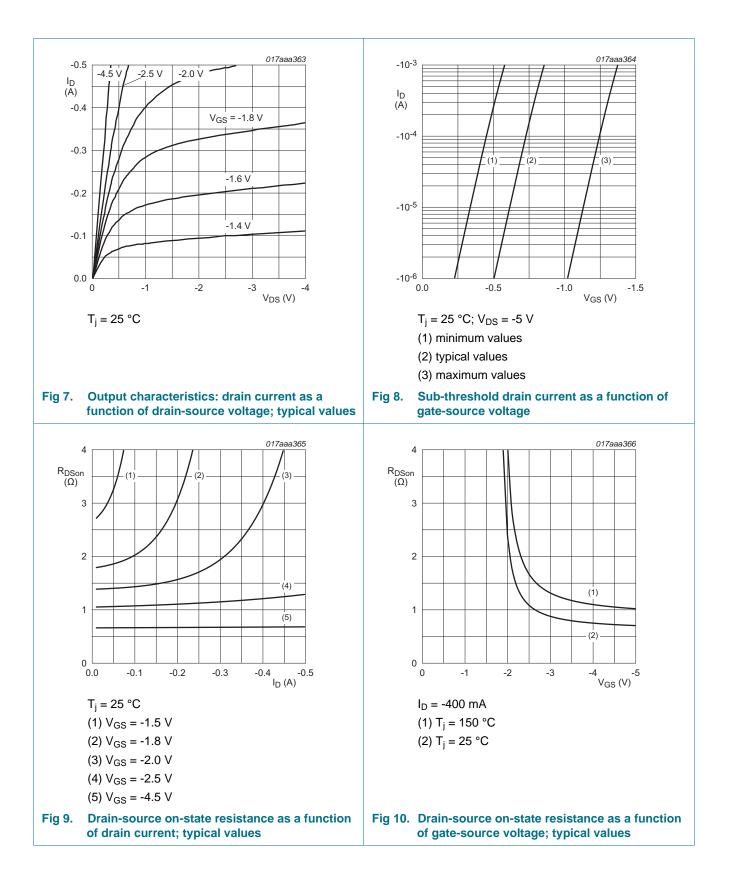


7. Characteristics

Table 7.	Characteristics	Conditions	Mim	Turn	Mov	4 ما ا
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
	aracteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = -250 \ \mu\text{A}; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^\circ\text{C}$	-20	-	-	V
V _{GSth}	gate-source threshold voltage	$I_D = -250 \ \mu\text{A}; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^\circ\text{C}$	-0.5	-0.9	-1.3	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
		V _{DS} = -20 V; V _{GS} = 0 V; T _j = 150 °C	-	-	-10	μA
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-2	μA
		V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-2	μA
		$V_{GS} = 4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-0.5	μA
		$V_{GS} = -4.5 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-0.5	μA
R _{DSon} drain-source resistance	drain-source on-state	V_{GS} = -4.5 V; I _D = -400 mA; T _j = 25 °C	-	0.67	0.85	Ω
	resistance	V_{GS} = -4.5 V; I _D = -400 mA; T _j = 150 °C	-	1.1	1.4	Ω
		V_{GS} = -2.5 V; I _D = -200 mA; T _j = 25 °C	-	1.2	1.5	Ω
		V_{GS} = -1.8 V; I _D = -10 mA; T _j = 25 °C	-	1.8	2.8	Ω
9 _{fs}	forward transconductance	V_{DS} = -10 V; I_{D} = -200 mA; T_{j} = 25 °C	-	610	-	mS
Dynamic	characteristics					
Q _{G(tot)}	total gate charge	$V_{DS} = -10 \text{ V}; \text{ I}_{D} = -400 \text{ mA};$	-	0.76	1.14	nC
Q _{GS}	gate-source charge	V _{GS} = -4.5 V; T _j = 25 °C	-	0.28	-	nC
Q _{GD}	gate-drain charge		-	0.18	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	58	87	pF
C _{oss}	output capacitance	T _j = 25 °C	-	21	-	pF
C _{rss}	reverse transfer capacitance		-	12	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; R_L = 250 Ω ; V_{GS} = -4.5 V;	-	18	36	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	30	-	ns
t _{d(off)}	turn-off delay time		-	80	160	ns
t _f	fall time		-	72	-	ns
Source-d	rain diode					
V _{SD}	source-drain voltage	I _S = -300 mA; V _{GS} = 0 V; T _i = 25 °C	-0.48	-0.84	-1.2	V

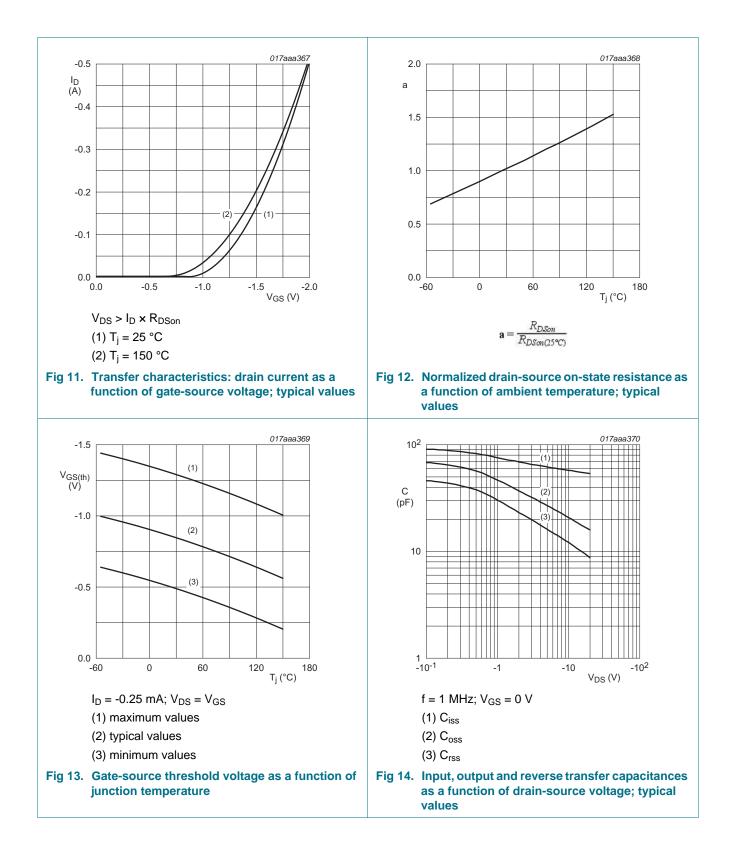
PMZB670UPE

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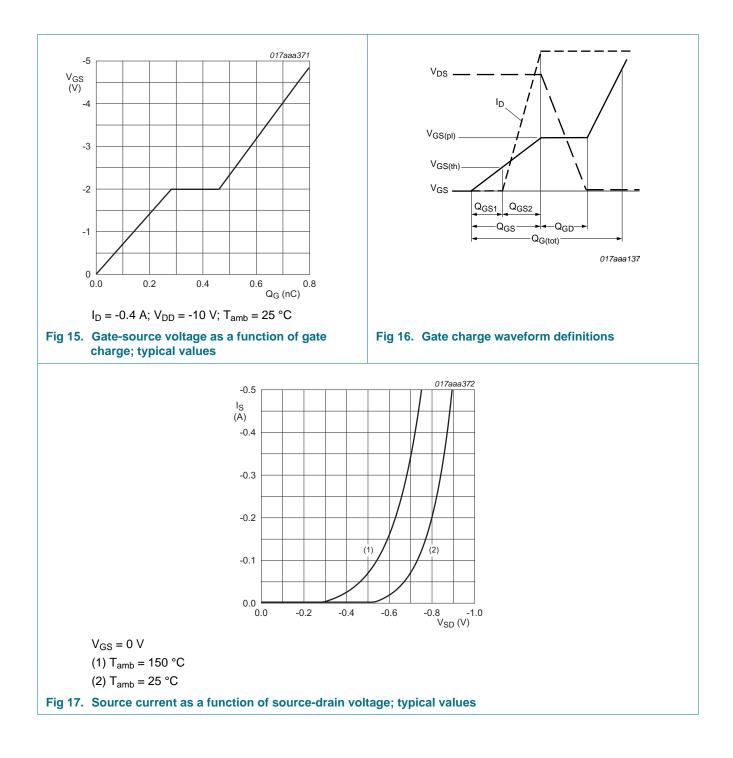
PMZB670UPE

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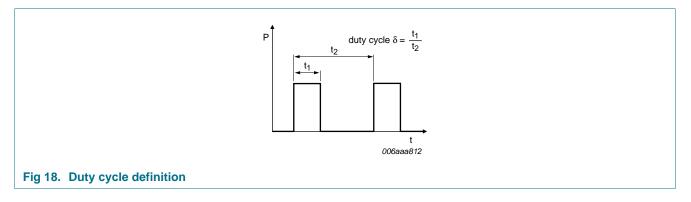
PMZB670UPE

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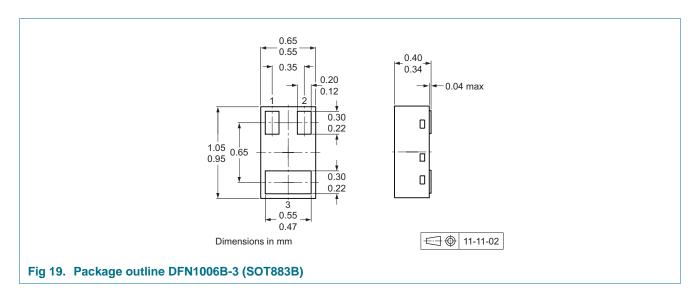


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8. Test information

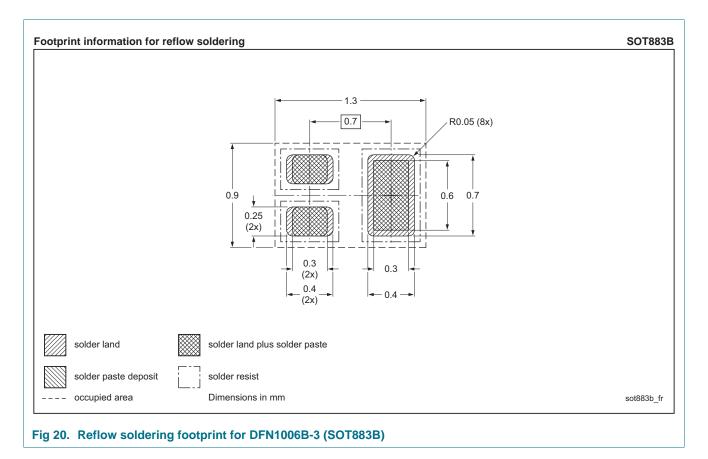


9. Package outline



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10. Soldering



11. Revision history

Table 8. Revision	history			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMZB670UPE v.3	20120323	Product data sheet	-	PMZB670UPE v.2
Modifications:	 1.2 "Features 	and benefits" is corrected.		
PMZB670UPE v.2	20120207	Product data sheet	-	PMZB670UPE v.1
PMZB670UPE v.1	20120131	Product data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status[1] [2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Product data sheet

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